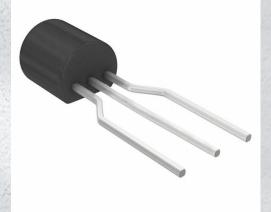


PN2222ATF Datasheet

www.digi-electronics.com



PN2222ATF-DG
onsemi
PN2222ATF
TRANS NPN 40V 1A TO92-3
Bipolar (BJT) Transistor NPN 40 V 1 A 300MHz 625 m W Through Hole TO-92-3

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PN2222ATF	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	1 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
40 V	1V @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
10nA (ICBO)	100 @ 150mA, 10V
Power - Max:	Frequency - Transition:
625 mW	300MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-226-3, TO-92-3 (TO-226AA) Formed Leads	TO-92-3
Base Product Number:	
PN2222	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	Not Applicable
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	



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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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PN2222A NPN General-Purpose Amplifier

Features

· This device is for use as a medium power amplifier and switch requiring collector currents up to 500mA.



Ordering Information

Part Number	Top Mark	Package	Packing Method
PN2222ABU	PN2222A	TO-92 3L	Bulk
PN2222ATA	PN2222A	TO-92 3L	Ammo
PN2222ATF	PN2222A	TO-92 3L	Tape and Reel
PN2222ATFR	PN2222A	TO-92 3L	Tape and Reel

Absolute Maximum Ratings^{(1), (2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	75	V
V _{EBO}	Emitter-Base Voltage	6.0	V
۱ _C	Collector Current	1.0	Α
T _{STG}	Operating and Storage Junction Temperature Range	-55 to 150	°C

Note:

- 1. These rating are based on a maximum junction temperature of 150 °C.
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operation.

July 2014

Thermal Characteristics⁽³⁾

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Max.	Unit
Б	Total Device Dissipation	625	mW
PD	Derate Above 25°C	5.0	mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	83.3	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	200	°C/W

Note:

3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

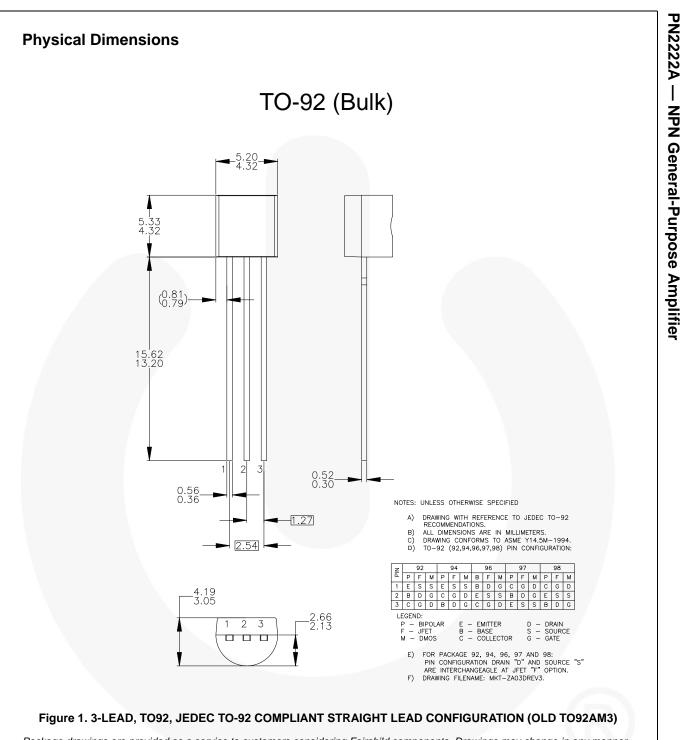
Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Uni
Off Charact	eristics			•	
BV _{(BR)CEO}	Collector-Emitter Breakdown Voltage ⁽⁴⁾	I _C = 10 mA, I _B = 0	40		V
BV _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 10 μA, I _E = 0	75		V
BV _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, \ I_{C} = 0$	6.0		V
ICEX	Collector Cut-Off Current	V _{CE} = 60 V, V _{EB(off)} = 3.0 V		10	nA
1	Collector Cut-Off Current	$V_{CB} = 60 \text{ V}, I_{E} = 0$		0.01	
I _{CBO}		$V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0, \text{ T}_{A} = 125^{\circ}\text{C}$		10	μΑ
I _{EBO}	Emitter Cut-Off Current	V _{EB} = 3.0 V, I _C = 0		10	nA
I _{BL}	Base Cut-Off Current	$V_{CE} = 60 \text{ V}, V_{EB(off)} = 3.0 \text{ V}$		20	nA
On Characte	eristics				
		$I_{C} = 0.1 \text{ mA}, V_{CE} = 10 \text{ V}$	35		
		$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}$	50]
		$I_{C} = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	75		
h _{FE} DC	DC Current Gain	$I_{C} = 10 \text{ mA}, V_{CE} = 10 \text{ V}, T_{A} = -55^{\circ}\text{C}$	35		
		$I_{\rm C}$ = 150 mA, $V_{\rm CE}$ = 10 V ⁽⁴⁾	100	300	T .
		$I_{\rm C}$ = 150 mA, $V_{\rm CE}$ = 1 V ⁽⁴⁾	50		1
		$I_{\rm C}$ = 500 mA, $V_{\rm CE}$ = 10 V ⁽⁴⁾	40		
M	Collector-Emitter Saturation Voltage ⁽⁴⁾	I _C = 150 mA, I _B = 15 mA		0.3	v
V _{CE(sat)}		I _C = 500 mA, I _B = 50 mA		1.0	, v
V	Base-Emitter Saturation Voltage ⁽⁴⁾	I _C = 150 mA, I _B = 15 mA	0.6	1.2	v
V _{BE(sat)}	Base-Emilier Saturation voltage	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		2.0	Ň
Small Signa	I Characteristics				
f _T	Current Gain Bandwidth Product	I _C = 20 mA, V _{CE} = 20 V, f = 100 MHz	300		МН
C _{obo}	Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 1 MHz		8.0	pF
C _{ibo}	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1 \text{ MHz}$		25	pF
rb'C _c	Collector Base Time Constant	I _C = 20 mA, V _{CB} = 20 V, f = 31.8 MHz		150	pS
NF	Noise Figure	I_{C} = 100 μA, V _{CE} = 10 V, R _S = 1.0 kΩ, f = 1.0 kHz		4.0	dB
Re(h _{ie})	Real Part of Common-Emitter High Frequency Input Impedance	I _C = 20 mA, V _{CE} = 20 V, f = 300 MHz		60	Ω
Switching C	Characteristics				
t _d	Delay Time	V _{CC} = 30 V, V _{EB(off)} = 0.5 V,		10	ns
t _r	Rise Time	$I_{\rm C} = 150 \text{ mA}, I_{\rm B1} = 15 \text{ mA}$		25	ns
t _s	Storage Time	V _{CC} = 30 V, I _C = 150 mA,		225	ns
t _f	Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}$		60	ns

Note:

4. Pulse test: pulse width $\leq 300~\mu s,$ duty cycle $\leq 2.0\%.$

PN2222A — NPN General-Purpose Amplifier

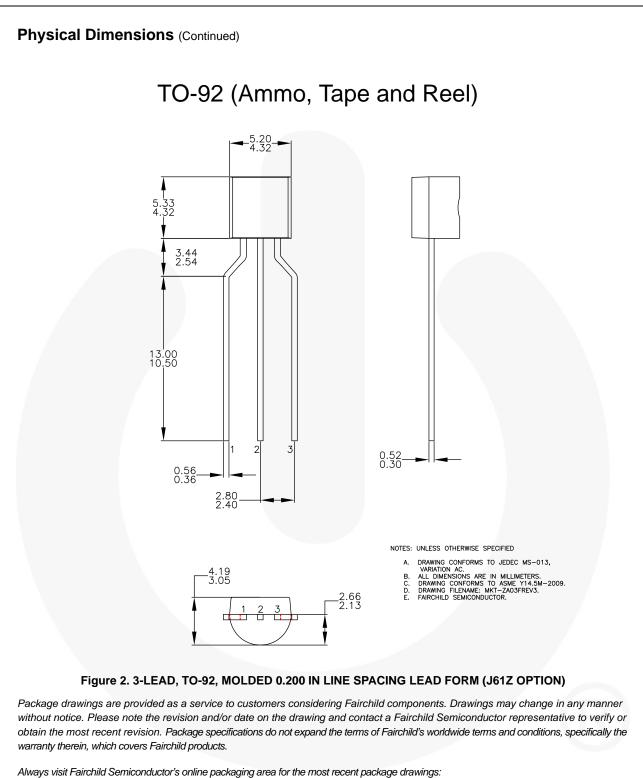


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